NSN 5961-01-311-3157

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-311-3157 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.300 inches **Terminal Length:** Between 1.000 inches and 1.500 inches **Overall Diameter:** Between 0.092 inches and 0.130 inches **Function For Which Designed:** Voltage regulator **Mounting Method: Terminal Features Provided:** Electrostatic sensitive and burn in **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 6.2 regulator voltage **Voltage Tolerance In Percent:** -1.0/+1.0**Current Rating Per Characteristic:** 1.00 milliamperes all primaries horsepower metric **Power Rating Per Characteristic:** 400.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 54497-0191a0029 manufacturers specification control Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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